

**Product data sheet** 

## 1. Product profile

### 1.1 General description

PESD1LIN in a very small SOD323 (SC-76) Surface-Mounted Device (SMD) plastic package designed to protect one automotive Local Interconnect Network (LIN) bus line from the damage caused by ElectroStatic Discharge (ESD) and other transients.

### 1.2 Features

- ESD protection of one automotive LIN bus line
- Asymmetrical diode configuration ensures an optimized ElectroMagnetic Immunity (EMI) of a LIN Electronic Control Unit (ECU)
- Due to the integrated diode structure only one very small SOD323 package is needed
- Max. peak pulse power:  $P_{PP} = 160 \text{ W}$  at  $t_p = 8/20 \text{ μs}$
- Low clamping voltage: V<sub>CL</sub> = 40 V at I<sub>PP</sub> = 1 A
- Ultra low leakage current: I<sub>RM</sub> < 1 nA
- ESD protection of up to 23 kV
- IEC 61000-4-2, level 4 (ESD)
- IEC 61000-4-5 (surge);  $I_{PP} = 3$  A at  $t_p = 8/20$  μs

## 1.3 Applications

- LIN bus protection
- Automotive applications

### 1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RWM}$	reverse standoff voltage					
	PESD1LIN (15 V)		-	-	15	V
	PESD1LIN (24 V)		-	-	24	V
$C_d$	diode capacitance	$V_R = 0 V;$ f = 1 MHz	-	13	17	pF



# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode 1 (15 V)		
2	cathode 2 (24 V)	1 2	1 2 006aab041

# 3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
PESD1LIN	SC-76	plastic surface-mounted package; 2 leads	SOD323			

# 4. Marking

Table 4. Marking codes

Type number	Marking code
PESD1LIN	AM

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$P_{PP}$	peak pulse power	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	160	W
I <sub>PP</sub>	peak pulse current	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	3	Α
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–65</b>	+150	°C
T <sub>stg</sub>	storage temperature		<b>–65</b>	+150	°C

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.



Table 6. ESD maximum ratings

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1] -	23	kV
		MIL-STD-883 (human body model)	-	10	kV

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

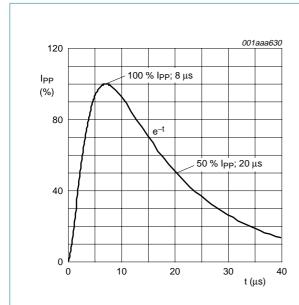


Fig 1. 8/20 µs pulse waveform according to IEC 61000-4-5

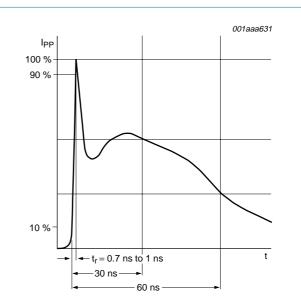


Fig 2. ESD pulse waveform according to IEC 61000-4-2

## 6. Characteristics

Table 8. Characteristics

 $T_{amb}$  = 25 °C unless otherwise specified.

· arrib — -							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{\text{RWM}}$	reverse standoff voltage						
	PESD1LIN (15 V)			-	-	15	V
	PESD1LIN (24 V)			-	-	24	V
I <sub>RM</sub>	reverse leakage current						
	PESD1LIN (15 V)	$V_{RWM} = 15 V$		-	< 1	50	nA
	PESD1LIN (24 V)	$V_{RWM} = 24 V$		-	< 1	50	nA
$V_{BR}$	breakdown voltage	$I_R = 5 \text{ mA}$					
	PESD1LIN (15 V)			17.1	18.9	20.3	V
	PESD1LIN (24 V)			25.4	27.8	30.3	V
C <sub>d</sub>	diode capacitance	$V_R = 0 V$ ; $f = 1 MHz$		-	13	17	pF
$V_{CL}$	clamping voltage		<u>[1]</u>				
	PESD1LIN (15 V)	I <sub>PP</sub> = 1 A		-	-	25	V
		I <sub>PP</sub> = 5 A		-	-	44	V
	PESD1LIN (24 V)	I <sub>PP</sub> = 1 A		-	-	40	V
		I <sub>PP</sub> = 3 A		-	-	70	V
r <sub>dif</sub>	differential resistance						
	PESD1LIN (15 V)	$I_R = 1 \text{ mA}$		-	-	225	Ω
	PESD1LIN (24 V)	$I_R = 1 \text{ mA}$		-	-	300	Ω

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

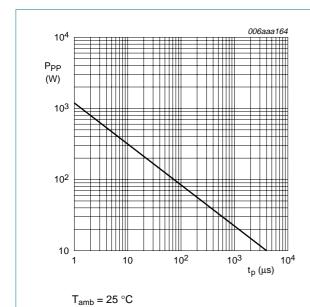


Fig 3. Peak pulse power as a function of exponential pulse duration; typical values

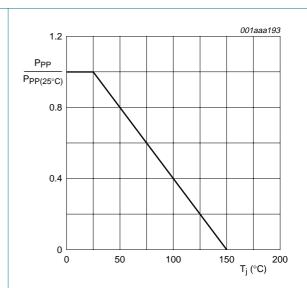


Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values

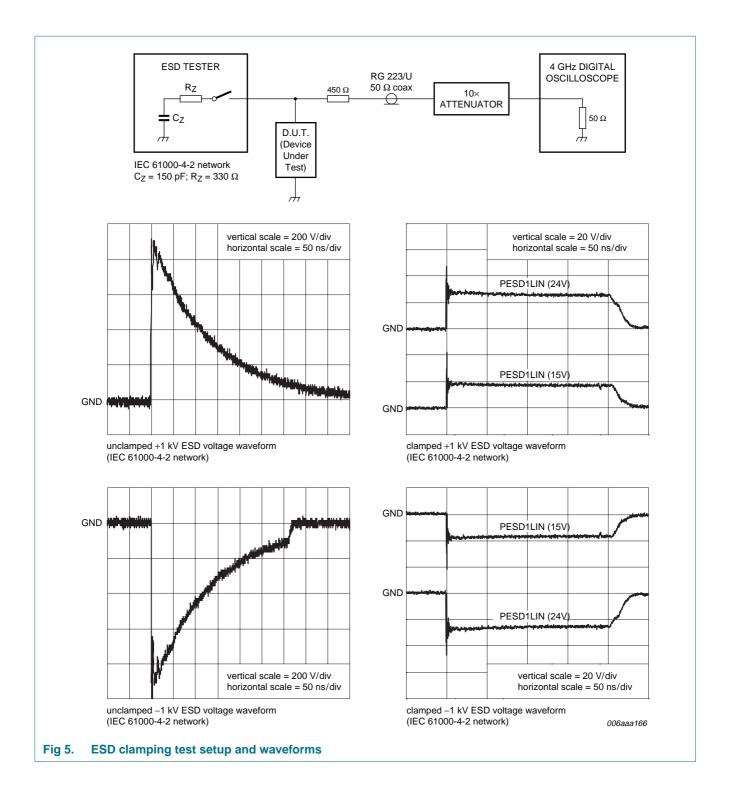
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**Product data sheet** 



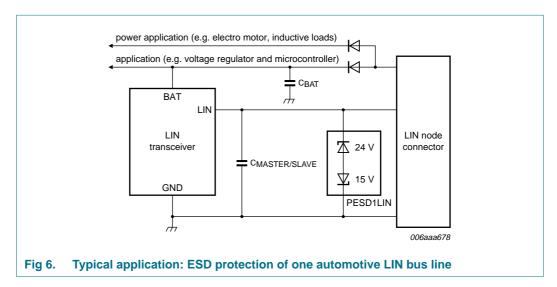
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### LIN bus ESD protection diode



## 7. Application information

The PESD1LIN is designed for the protection of one LIN bus signal line from the damage caused by ESD and surge pulses. The PESD1LIN provides a surge capability of up to 160 W per line for a  $8/20 \mu \text{s}$  waveform.

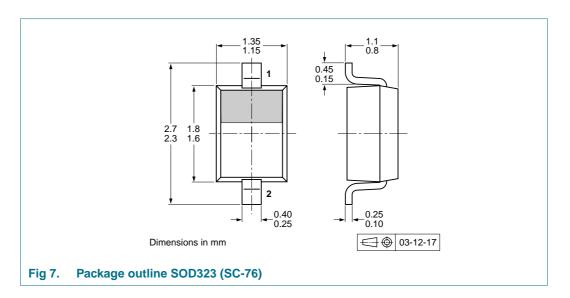


#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PESD1LIN as close to the input terminal or connector as possible.
- 2. The path length between the PESD1LIN and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protection conductors in parallel with unprotected conductor.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

# Package outline



#### **Packing information** 9.

**Packing methods** Table 9.

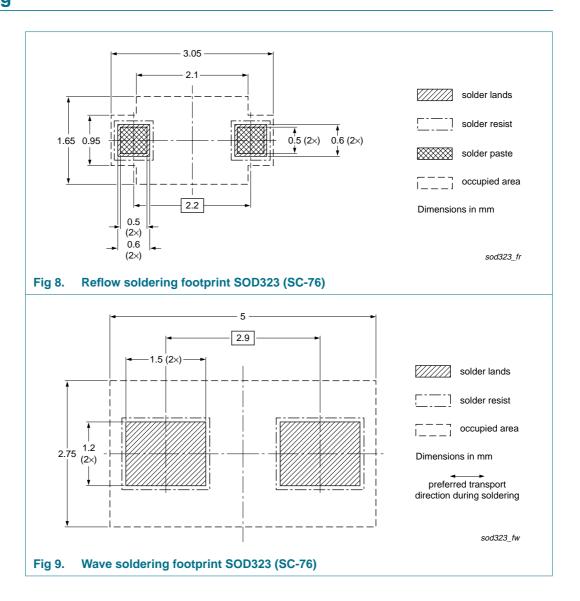
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing q	uantity
			3000	10000
PESD1LIN	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 13.



# 10. Soldering





# 11. Revision history

## Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD1LIN_2	20081112	Product data sheet	-	PESD1LIN_1
Modifications:		f this data sheet has been re	edesigned to comply w	rith the new identity
<ul> <li>Legal texts have been adapted to the new company name where appropria</li> </ul>				
	<ul> <li><u>Table 6</u>: ESD electrostatic discharge capability redefined to V<sub>ESD</sub> electrostatic d voltage</li> </ul>			
	<ul> <li>Figure 6: enh</li> </ul>	nanced		
	<ul> <li>Figure 7: sup</li> </ul>	perseded by minimized pack	age outline drawing	
	<ul> <li>Section 10 "S</li> </ul>	Soldering": added		
	<ul> <li>Section 12 "L</li> </ul>	<u>egal information</u> ": updated		
PESD1LIN_1	20041026	Product data sheet	-	-

## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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